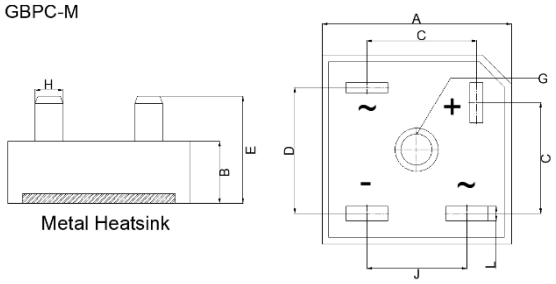
GBPC35 SERIES

35A Glass Passivated Single Phase Bridge Rectifiers

Features

- Glass Passivated Die Construction
- Low Reverse Leakage Current
- Low Power Loss, High Efficiency
- Heatsink Integrated Epoxy Case for
- Maximum Heat Dissipation
- Low Thermal Resistance
- High Surge Current Capability
- Recognized File

GBPC-M



Mechanical Data

- Case: Epoxy Case with Heatsink, Available in Both Low Profile and Standard Case Height
- Terminals: Plated Faston Lugs or Wire Leads, Add "W" Suffix to Indicate Wire Leads
- Polarity: As Marked on Case
- Mounting: Through Hole with #10 Screw
- Mounting Torque: 2.0 N.m Max.
- Weight: 20.06grams (GBPC-M);
- Marking: Type Number
- **Lead Free: For RoHS / Lead Free Version, Add "-LF" Suffix to Part Number, See Page 4**

	GBPC-M Low Profile / Standard	
Dim	**Min**	**Max**
A	28.20	28.80
B	7.65	8.15
C	15.30	17.30
D	17.10	19.10
E	12.65	12.85
G	Hole for #10 screw, 5.08Ø Nominal	
H	4.0 Typical	
J	13.20	15.20
L	0.72	0.82
All Dimension in mm		

Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	GBPC35										Unit
		00	01	02	04	06	08	10	12	14	16	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	50	100	200	400	600	800	1000	1200	1400	1600	V
RMS Reverse Voltage	$V_{R(RMS)}$	35	70	140	280	420	560	700	840	980	1120	V
Average Rectified Output Current @T_C = 55°C	I_O	35										A
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load (JEDEC Method)	I_{FSM}	400										A
Forward Voltage per leg @I_F = 17.5A	V_{FM}	1.1										V
Peak Reverse Current @T_C = 25°C At Rated DC Blocking Voltage @T_C = 125°C	I_{RM}	10 500										μA
I^2t Rating for Fusing (t < 8.3ms)	I^2t	660										A^2s
Typical Junction Capacitance (Note 1)	C_J	300										pF
Typical Thermal Resistance (Note 2)	$R_{\theta JC}$	1.4										°C/W
RMS Isolation Voltage, t = 1min	V_{ISO}	2500										V
Operating and Storage Temperature Range	T_J, T_{STG}	-55 to +150										℃

Note: 1. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.
2. Thermal resistance junction to case, mounted on 241 x 89 x 117mm Al. heatsink.

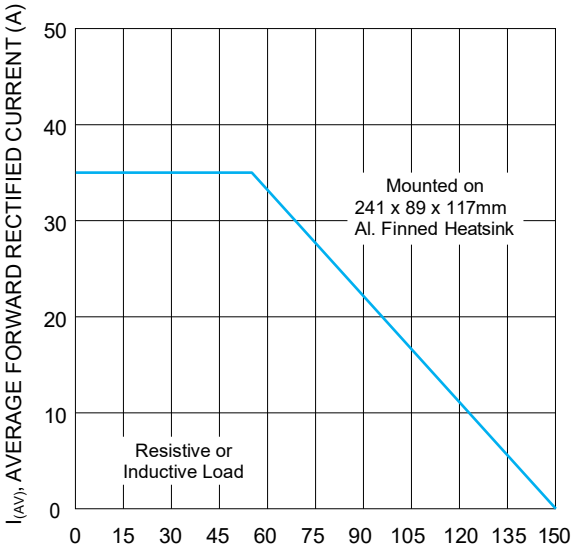


Fig. 1 Forward Current Derating Curve

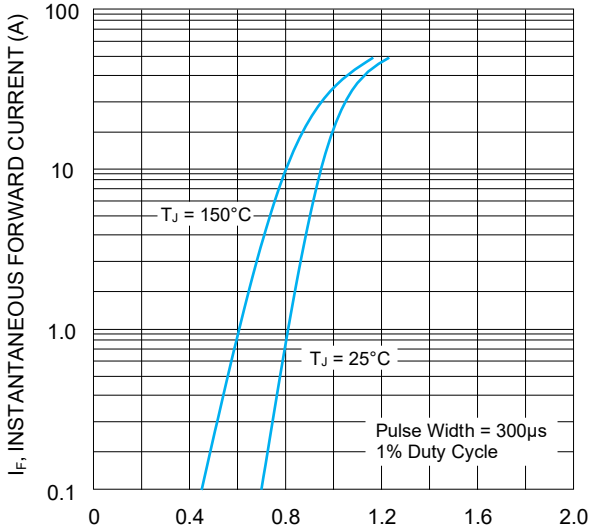


Fig. 2 Typical Forward Characteristics

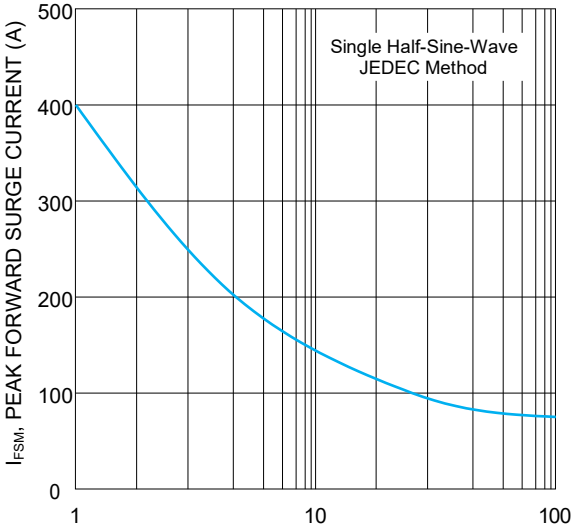


Fig. 3 Forward Surge Current Derating Curve

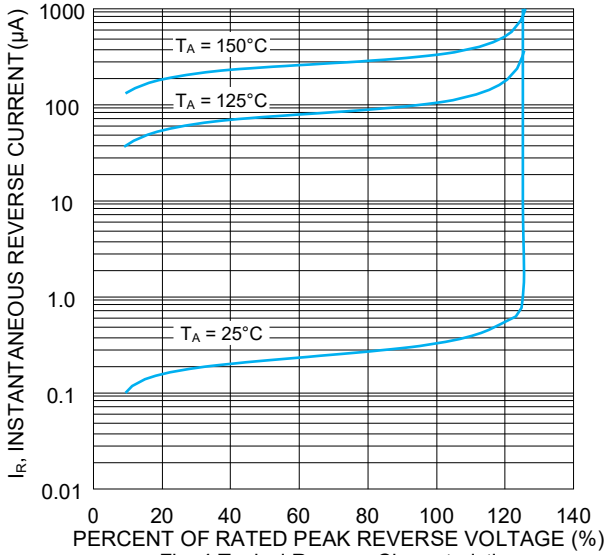


Fig. 4 Typical Reverse Characteristics

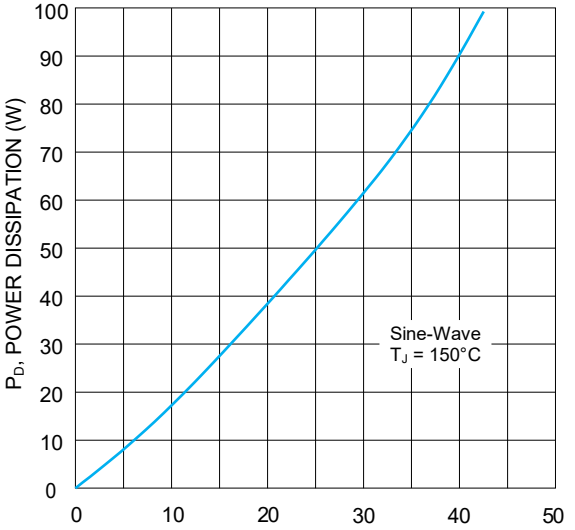


Fig. 5 Forward Power Dissipation

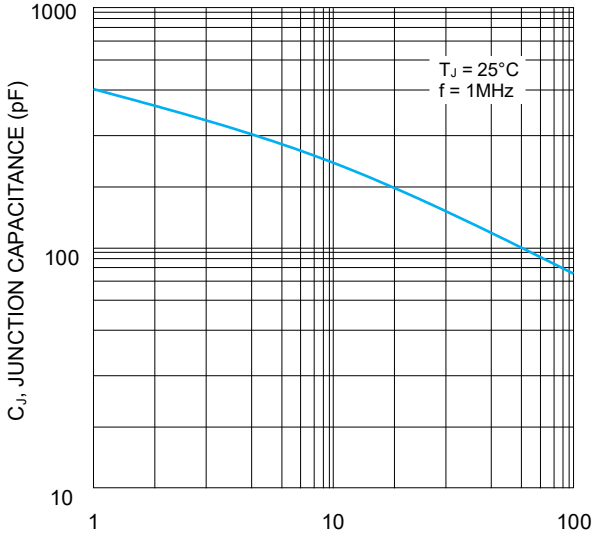
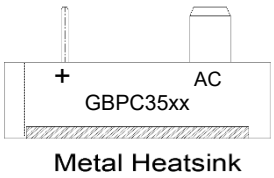


Fig. 6 Typical Junction Capacitance

MARKING INFORMATION

GBPC-M



GBPC35xx = Device Number
xx = 00, 01, 02, 04, 06, 08, 10, 12, 14 or 16
Polarity = As Marked on Body

PACKAGING INFORMATION

BULK

Case Style	Inner Box Size L x W x H (mm)	Quantity (PCS)	Carton Size L x W x H (mm)	Quantity (PCS)	Approx. Gross Weight (KG)
GBPC-M	210 x 210 x 40	50	430 x 215 x 220	500	12.0

Note: 1. Paper box, white or brown color.

ORDERING INFORMATION

Product No.	Package Type	Shipping Quantity
GBPC35xx	Square Bridge	50 Units/Box

Shipping quantity given is for minimum packing quantity only. For minimum order quantity, please consult the Sales Department.

Please Read Carefully

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